

New Jersey Semi-Conductor Products, Inc.

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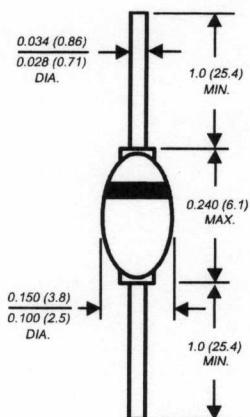
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1N5614 THRU 1N5622

GLASS PASSIVATED MEDIUM-SWITCHING JUNCTION RECTIFIER

Reverse Voltage - 200 to 1000 Volts **Forward Current - 1.0. Ampere**

DO-204AP



Dimensions in inches and (millimeters)

FEATURES

- ◆ High temperature metallurgically bonded construction
- ◆ 1.0 Ampere operation at TA= 55°C with no thermal runaway
- ◆ Typical IR less than 0.1µA
- ◆ Hermetically sealed package
- ◆ Capable of meeting environmental standards of MIL-S-19500
- ◆ High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension



MECHANICAL DATA

Case: JEDEC DO-204AP solid glass body

Terminals: Solder plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.02 ounce, 0.56 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	1N5614	1N5616	1N5618	1N5620	1N5622	UNITS
* Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	140	280	420	560	700	Volts
* Maximum DC blocking voltage	V _D C	200	400	600	800	1000	Volts
* Minimum reverse breakdown voltage at 50µA	V _{BR}	220	440	660	880	1100	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA=55°C	I _(AV)				1.0		Amp
* Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}				50.0		Amps
* Maximum instantaneous forward voltage at 1.0A	V _F			1.2			Volts
* Maximum DC reverse current TA=25°C				0.5			
at rated DC blocking voltage TA=100°C	I _R			25.0			µA
TA=200°C				1500			
* Maximum reverse recovery time (NOTE 1)	t _{rr}			2.0			µs
Maximum junction capacitance (NOTE 2)	C _J	45	35	25	20	15	pF
Typical thermal resistance (NOTE 3)	R _{θJA}			55.0			°C/W
* Operating junction temperature range	T _J			-65 to +175			°C
* Storage temperature range	T _{STG}			-65 to +200			°C

NOTES:

(1) Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_{rr}=0.25A

(2) Measured at 1.0 MHz and applied reverse voltage of 12 Volts

(3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length P.C.B. mounted

*JEDEC registered values